



# High cost-performance DIP8-pin type with reinforced insulation

PhotoMOS Relays

GU-E 2 Form A

(AQW210EH)



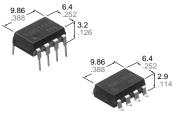
### **FEATURES**

# 1. Reinforced insulation of 5,000 V More than 0.4 mm internal insulation distance between inputs and outputs. Conforms to EN41003, EN60950 (reinforced insulation).

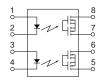
- 2. Applicable for 2 Form A use as well as two independent 1 Form A use
- 3. Controls low-level analog signals PhotoMOS relays feature extremely low closed-circuit offset voltage to enable control of low-level analog signals without distortion.
- 4. High sensitivity and high speed response

Can control max. 0.14 A load current with 5 mA input current. Fast operation speed of typ. 0.5 ms (AQW210EH).

5. Low-level off state leakage current of max. 1  $\mu\text{A}$ 



mm inch



**Compliance with RoHS Directive** 

### TYPICAL APPLICATIONS

- Modem
- Telephone equipment
- Security equipment
- Sensing equipment

#### **TYPES**

	I/O isolation voltage	Output rating*		- Package	Part No.					
					Through hole terminal	Surface-mount terminal			Packing quantity	
		Load Load voltage currer	Lood	rackage			Tape and reel packing style			
			current		Tube pac	cking style	Picked from the 1/2/3/4-pin side	Picked from the 5/6/7/8-pin side	Tube	Tape and reel
AC/DC dual use	Reinforced 5,000 V	60 V	500 mA		AQW212EH	AQW212EHA	AQW212EHAX	AQW212EHAZ	1 tube contains:	
		rced 350 V 120 mA	DIP8-pin	AQW210EH	AQW210EHA	AQW210EHAX	AQW210EHAZ	40 pcs.	1,000 pcs.	
		400 V	100 mA	] '	AQW214EH	AQW214EHA	AQW214EHAX	AQW214EHAZ	1 batch contains: 400 pcs.	1,000 pcs.
		600 V	40 mA		AQW216EH	AQW216EHA	AQW216EHAX	AQW216EHAZ		

<sup>\*</sup>Indicate the peak AC and DC values.

Note: The surface mount terminal shape indicator "A" and the packing style indicator "X" or "Z" are not marked on the relay.

#### **RATING**

1. Absolute maximum ratings (Ambient temperature: 25°C 77°F)

Item		Symbol	AQW212EH(A)	AQW210EH(A)	AQW214EH(A)	AQW216EH(A)	Remarks
	LED forward current	lF					
Input	LED reverse voltage	VR					
	Peak forward current	IFP		f =100 Hz, Duty factor = 0.1%			
	Power dissipation	Pin					
Output	Load voltage (peak AC)	VL	60 V	350 V	400 V	600 V	
	Continuous load current	lı.	0.5 A (0.6 A)	0.12 A (0.14 A)	0.1 A (0.13 A)	0.04 A (0.05 A)	Peak AC, DC (): in case of using only 1 channel
	Peak load current	Ipeak	1.5 A	0.36 A	0.3 A	0.15 A	100 ms (1 shot), V <sub>L</sub> = DC
	Power dissipation	Pout					
Total pov	ver dissipation	Рт					
I/O isolation voltage		Viso					
Tempera	ture Operating	Topr		Non-condensing at low temperatures			
limits	Storage	Tstg					

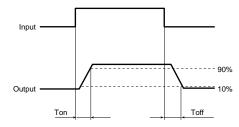
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## GU-E 2 Form A (AQW21OEH)

#### 2. Electrical characteristics (Ambient temperature: 25°C 77°F)

Item			Symbol	AQW212EH(A)	AQW210EH(A)	AQW214EH(A)	AQW216EH(A)	Condition
Input	LED operate current	Typical	IFon		l∟=Max.			
	LED operate current	Maximum			IL=IVIAX.			
	LED turn off current	Minimum	l Foff		IL=Max.			
	LED turn on current	Typical			IL=IVIAX.			
	LED dropout voltage	Typical	VF		· I==50mA			
	LED dropout voltage	Maximum	VF	1.5V				
Output	0	Typical	Ron	0.83Ω	18Ω	26Ω	52Ω	I <sub>F</sub> =5mA I <sub>L</sub> =Max. Within 1 s on time
	On resistance	Maximum		2.5Ω	25Ω	35Ω	120Ω	
·	Off state leakage current Maxim		ILeak	1μΑ			I <sub>F</sub> =0mA V <sub>L</sub> =Max.	
	Turn on time*	Typical	Ton	1ms	0.5ms		I <sub>F</sub> =5mA	
Transfer characteristics	Turn on time	Maximum	Ion	4ms		2.0ms		I∟=Max.
	Turn off time*	Typical	Toff	0.08ms 0.04ms			I <sub>F</sub> =5mA	
	Turri on time	Maximum	I Off	1.0ms				I∟=Max.
	I/O capacitance	Typical	Ciso	0.8pF				f =1MHz
	1/О сараснансе	Maximum	Ciso	1.5pF				V <sub>B</sub> =0V
	Initial I/O isolation resistance Minimum		Riso	1,000ΜΩ			500V DC	

<sup>\*</sup>Turn on/Turn off time



#### RECOMMENDED OPERATING CONDITIONS

Please obey the following conditions to ensure proper relay operation and resetting.

Item	Symbol	Recommended value	Unit	
Input LED current	lF	5 to 10	mA	

- **■** For Dimensions
- **■** For Schematic and Wiring Diagrams
- **■** For Cautions for Use
- These products are not designed for automotive use.

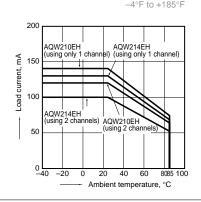
If you are considering to use these products for automotive applications, please contact your local Panasonic Electric Works technical representative.

For more information

#### REFERENCE DATA

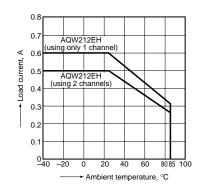
1-(1). Load current vs. ambient temperature characteristics

Allowable ambient temperature: -20°C to +85°C



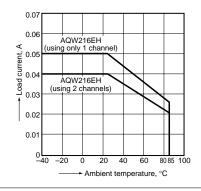
1-(2). Load current vs. ambient temperature characteristics

Allowable ambient temperature: -40°C to +85°C -40°F to +185°F



1-(3). Load current vs. ambient temperature characteristics

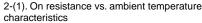
Allowable ambient temperature: -40°C to +85°C -40°F to +185°F



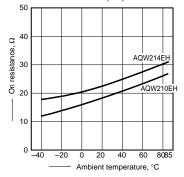
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### GU-E 2 Form A (AQW21OEH)

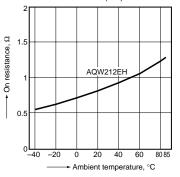


Measured portion: between terminals 5 and 6, 7 and 8; LED current: 5 mA; Load voltage: Max. (DC); Continuous load current: Max. (DC)



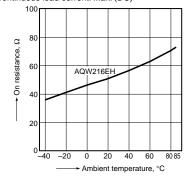
2-(2). On resistance vs. ambient temperature characteristics

Measured portion: between terminals 5 and 6, 7 and 8; LED current: 5 mA; Load voltage: Max. (DC); Continuous load current: Max. (DC)



2-(3). On resistance vs. ambient temperature characteristics

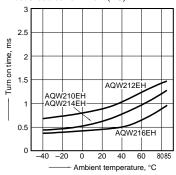
Measured portion: between terminals 5 and 6, 7 and 8; LED current: 5 mA; Load voltage: Max. (DC); Continuous load current: Max. (DC)



### 3. Turn on time vs. ambient temperature characteristics

Sample: All types

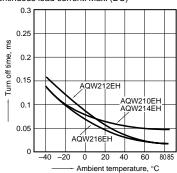
LED current: 5 mA; Load voltage: Max. (DC); Continuous load current: Max. (DC)



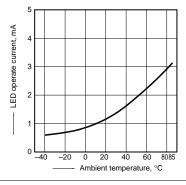
4. Turn off time vs. ambient temperature characteristics

Sample: All types

LED current: 5 mA; Load voltage: Max. (DC); Continuous load current: Max. (DC)

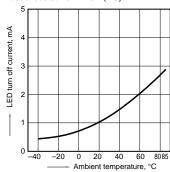


5. LED operate current vs. ambient temperature characteristics Sample: All types; Load voltage: Max. (DC); Continuous load current: Max. (DC)

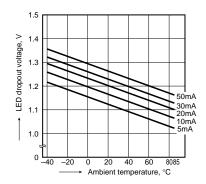


# 6. LED turn off current vs. ambient temperature characteristics Sample: All types; Load voltage: Max. (DC);

Continuous load current: Max. (DC)

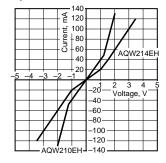


7. LED dropout voltage vs. ambient temperature characteristics Sample: All types; LED current: 5 to 50 mA



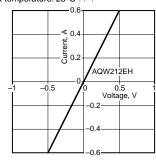
8-(1). Current vs. voltage characteristics of output at MOS portion

Measured portion: between terminals 5 and 6, 7 and 8; Ambient temperature: 25°C  $77^{\circ}F$ 



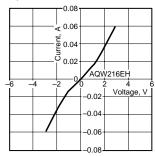
# 8-(2). Current vs. voltage characteristics of output at MOS portion

Measured portion: between terminals 3 and 4; Ambient temperature: 25°C 77°F



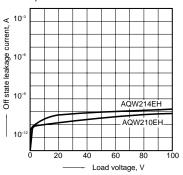
8-(3). Current vs. voltage characteristics of output at MOS portion

Measured portion: between terminals 3 and 4; Ambient temperature: 25°C 77°F



9-(1). Off state leakage current vs. load voltage characteristics

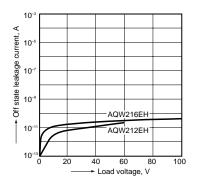
Measured portion: between terminals 5 and 6, 7 and 8; Ambient temperature: 25°C  $77^\circ F$ 



# GU-E 2 Form A (AQW21OEH)

9-(2). Off state leakage current vs. load voltage characteristics

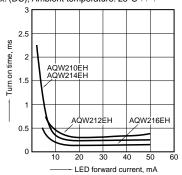
Measured portion: between terminals 5 and 6, 7 and 8; Ambient temperature: 25°C  $77^{\circ}F$ 



10. Turn on time vs. LED forward current characteristics

Sample: All types

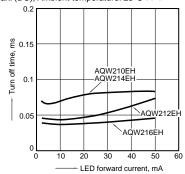
Measured portion: between terminals 5 and 6, 7 and 8; Load voltage: Max. (DC); Continuous load current: Max. (DC); Ambient temperature: 25°C  $77^{\circ}$ F



11. Turn off time vs. LED forward current characteristics

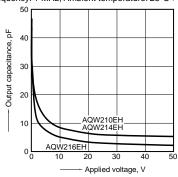
Sample: All types

Measured portion: between terminals 5 and 6, 7 and 8; Load voltage: Max. (DC); Continuous load current: Max. (DC); Ambient temperature: 25°C 77°F



12-(1). Output capacitance vs. applied voltage characteristics

Measured portion: between terminals 5 and 6, 7 and 8; Frequency: 1 MHz; Ambient temperature: 25°C 77°F



12-(2). Output capacitance vs. applied voltage characteristics

Measured portion: between terminals 5 and 6, 7 and 8; Frequency: 1 MHz; Ambient temperature: 25°C 77°F

